S1C33221/222



32-bit Single Chip Microcontroller

- High-speed 32-bit RISC Core
- Multiply Accumulation
- 10-bit ADC
- Built-in RAM
- High-speed DMA, Intelligent DMA
- Twin-clock Oscillator

■ DESCRIPTIONS

The S1C33221/222 is a CMOS 32-bit microcomputer composed of a CMOS 32-bit RISC core, ROM, RAM, DMA, timers, SIO, PLL and other circuits. The S1C33221/222 can be operated with high speed and spend little current. With the ADC, PWM and the MAC function, the S1C33221/222 is suitable for voice applications, PDAs and OA products such as printers.

■ FEATURES

● CMOS LSI 32-bit parallel processing S1C33000 RISC core

■ Main clock
50MHz (Max., up to 12.5MHz external clock input)

● Sub clock 32.768kHz (Typ., crystal)

● Instruction set 16-bit fixed length, 105 instructions

(MAC instruction is included, 2 cycles)

● Internal RAM size 8,192 bytes

● Internal ROM size 131,072 bytes (S1C33221), 65,536 bytes (S1C33222)

Clock timer 1 channel

◆ Programmable timer
 ◆ PWM timer
 ◆ Watchdog timer
 ★ 8 bits × 6 channels and 16 bits × 6 channels
 ★ Realized with a 16-bit programmable timer
 ★ Realized with a 16-bit programmable timer

Serial interface4 channels

Clock synchronization type and asynchronization type are selectable.

Usable as an infrared ray (IrDA) interface.

■ 10-bit A/D converter
Successive approximation type, 8 input channels

High-speed DMA
 Intelligent DMA
 I/O port
 I/O port
 I/O port : 30 bits

I/O port : 29 bits

Pins are shared with the inputs and outputs of built-in peripheral circuits.

● Interrupt controller External interrupts : 10 types Internal interrupts: 29 types

● External bus interface 24-bit address bus, 16-bit data bus, 7 chip enable pins

DRAM and burst ROM may be connected directly.

● Shipping form QFP15-128pin

● Supply voltage Core voltage: 1.8 to 3.6V

I/O voltage: 1.8 to 5.5V

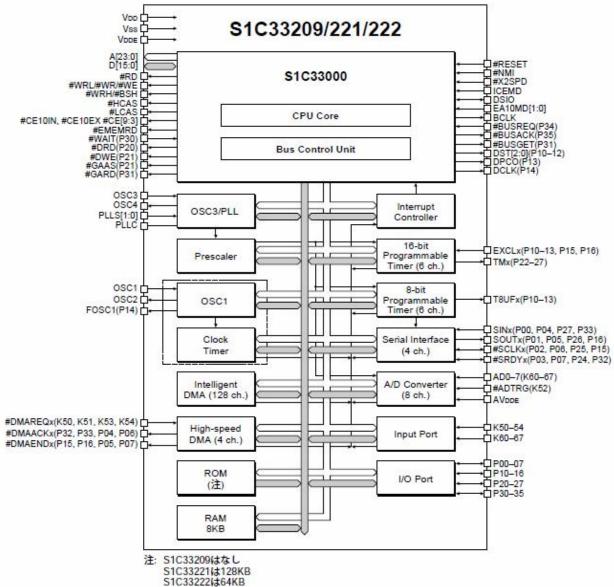
● Current consumption SLEEP state: 10µA (3.3V, 32.768kHz, clock timer run state, Typ.)

: 2.5µA (2.0V, 32.768kHz, clock timer run state, Typ.)

RUN state: 70mA (3.3V, 50MHz Typ.)

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■ Block Diagram



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Document code: 411875600 First issue Dec, 2009